



# TSS40L

# 0.2Amp Surface Mount Schottky Barrier Diode

# 1005





## **Features**

- Designed for mounting on small surface
- Extremely thin/leadless package
- Low capacitance
- Low forward voltage drop
- High temperature soldering: 260°C/10 seconds at terminals
- Chip version in 1005

## **Mechanical Data**

- Case: 1005 Standard package, molded plastic
- Terminals: Gold plated, solderable per MIL-STD-750, method 2026.
- Polarity: Indicated by cathode band
- Mounting position: Any Package code: RW
- Weight: 0.006 gram (approximately)

ITEM	1005
L	0.102(2.60)
	0.095(2.40)
W	0.051(1.30)
	0.043(1.10)
Т	0.035(0.90)
	0.027(0.70)
С	0.020(0.50)
	Typical
D	0.040(1.00)
	Typical

#### **Dimensions in inches and (millimeters)**

### Maximum Ratings TA=25 °C unless otherwise specified

Type Number	Symbol	1005	Units
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	40	V
Reverse Voltage	V <sub>R</sub>	40	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	28	V
Average Forward Current	I <sub>O</sub>	200	mA
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I <sub>FSM</sub>	600	mA
Power Dissipation	Pd	200	mW
Forward Voltage IF=1.0mA IF=40mA	V <sub>F</sub>	0.38 1.0	V
Reverse Leakage Current VR=30V	I <sub>R</sub>	0.2	uA
Typical capacitance between terminals VR=0V, f =1.0MHz reverse voltage	Сл	3	pF
Reverse Recovery Time (IF=IR=10mA, Irr=0.1x IR, RL=100Ω)	Trr	5	nS
Junction Temperature	TJ	-65 to + 125	°C
Storage Temperature	T <sub>STG</sub>	-65 to + 125	°C



### RATINGS AND CHARACTERISTIC CURVES(TSS40L)

Fig. 1 - Forward characteristics

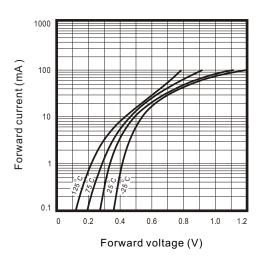


Fig.3 - Capacitance between terminals characteristics

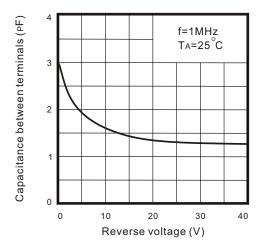


Fig. 2 - Reverse characteristics

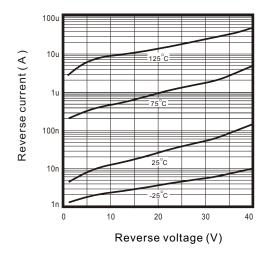
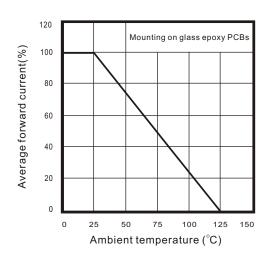


Fig.4 - Current derating curve



Version: A07

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